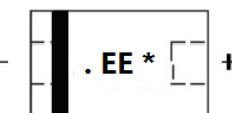


## WSB5512M

5A, Schottky Barrier Diode

[Http://www.sh-willsemi.com](http://www.sh-willsemi.com)

SMA (DO-214AC)



. EE = Device code

\* = Month code (A-Z)

Pin configuration and Marking

## MECHANICAL DATA

- Case: SMA molded plastic body
- Polarity: Color band denotes cathode end
- Mounting position: ANY

## Order information

Device	Package	Shipping
WSB5512M-2/TR	SMA (DO-214AC)	5000/Tape&Reel

### Absolute maximum ratings

Parameter	Symbol	Value	Unit
Maximum Repetitive Peak Reverse Voltage	$V_{RRM}$	40	V
Maximum RMS voltage	$V_{RWS}$	28	V
Maximum DC blocking voltage	$V_{DC}$	40	V
Maximum average forward rectified current at $T_L$ (Fig.2)	$I_{F(AV)}$	5.0	A
Peak forward surge current 8.3ms single half-sine-wave	$I_{FSM}$	150	A
Operating temperature range	$T_J$	-55 ~ 125	°C
Storage temperature range	$T_{STG}$	-55 ~ 150	°C

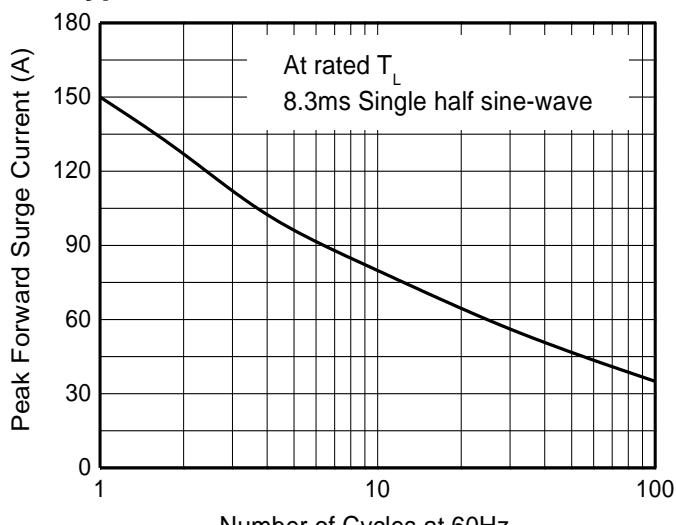
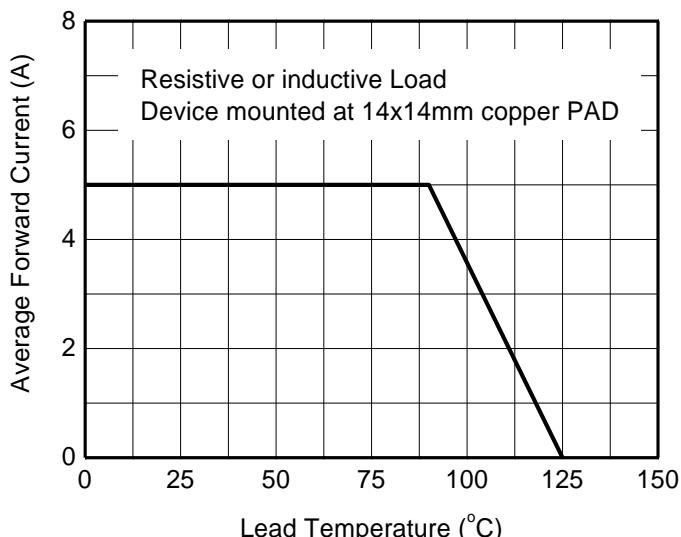
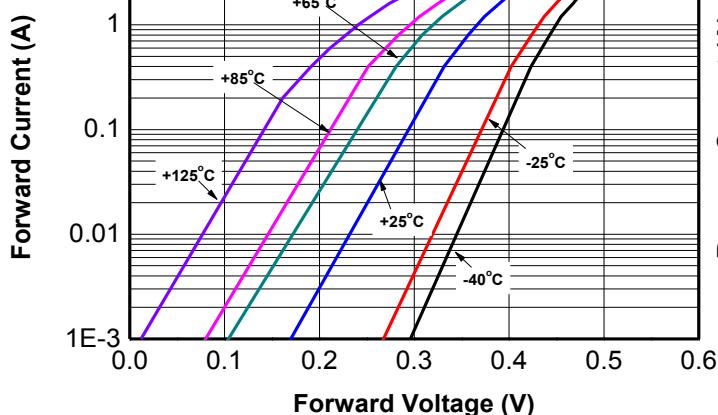
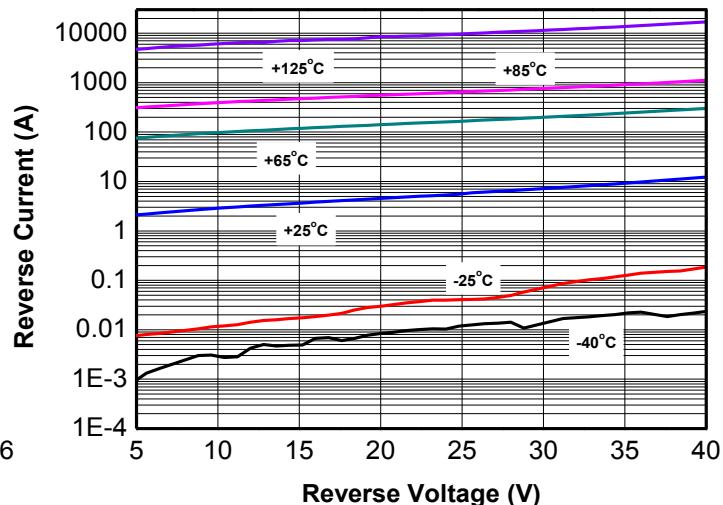
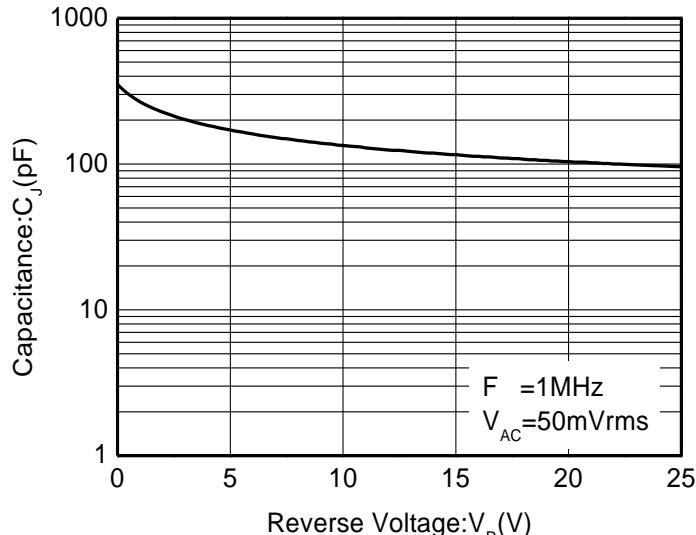
### Thermal Characteristics

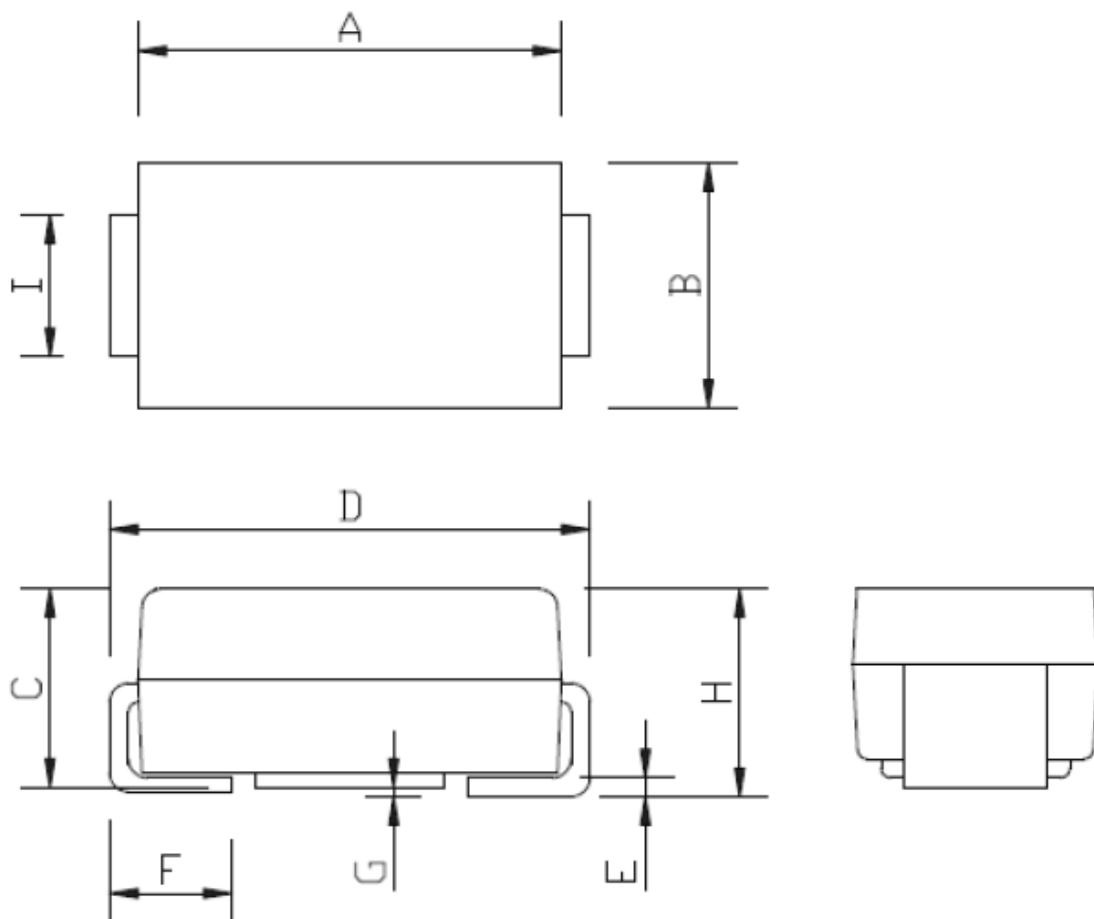
Parameter	Symbol	Value	Unit
Maximum thermal resistance (Junction to Lead)(Fig.2)	$R_{\theta JL}$	14	°C/W

### Electronics characteristics ( $T_A=25^\circ C$ )

Parameter	Symbol	Value	Unit
Maximum instantaneous forward voltage @ $I_F=5.0A^*$	$V_F$	0.55	V
Maximum reverse current @ $V_{DC}$ ( $T_J=25^\circ C$ )	$I_R$	0.5	mA
Maximum reverse current @ $V_{DC}$ ( $T_J=100^\circ C$ )	$I_R$	50	mA

\*: Pulse test, Pulse width 300us, duty cycle 1 %

**Typical characteristics ( $T_a=25^\circ\text{C}$ , unless otherwise noted)**

**Fig.1: Peak Forward Surge Current**

**Fig.2: Power Derating Curve**

**Fig.3: Typical Forward Characteristics**

**Fig.4: Typical Reverse Characteristics**

**Fig.5: Junction capacitance Vs. Reverse voltage**

**Package outline dimensions**
**SMA (DO-214AC)**


Symbol	Dimensions in millimeter	
	Min.	Max.
A	4.25	4.65
B	2.40	2.80
C	1.85	2.15
D	4.85	5.35
E	0.10	0.30
F	0.90	1.50
G	0.20 Max.	
H	1.90	2.30
I	1.35	1.65